

W53SED

SUPER BRIGHT ORANGE

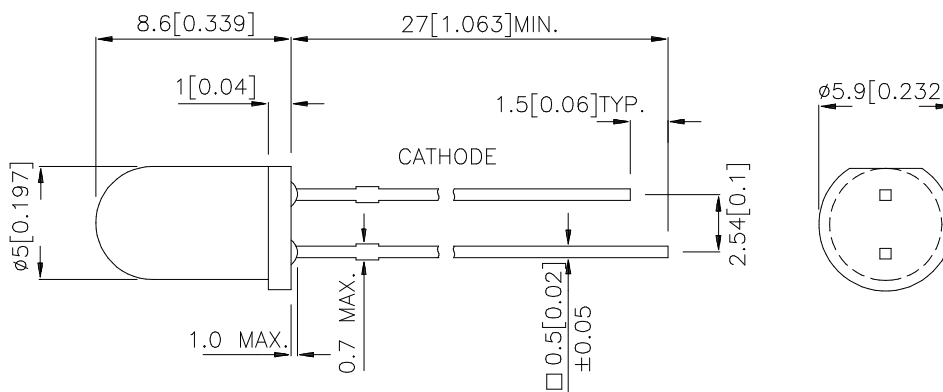
Features

- LOW POWER CONSUMPTION.
- POPULAR T-1 3/4 DIAMETER PACKAGE.
- GENERAL PURPOSE LEADS.
- RELIABLE AND RUGGED.
- LONG LIFE - SOLID STATE RELIABILITY.

Description

The Super Bright Orange source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @20 mA		Viewing Angle
			Min.	Typ.	θ1/2
W53SED	SUPER BRIGHT ORANGE (GaAsP/GaP)	ORANGE DIFFUSED	380	800	30°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

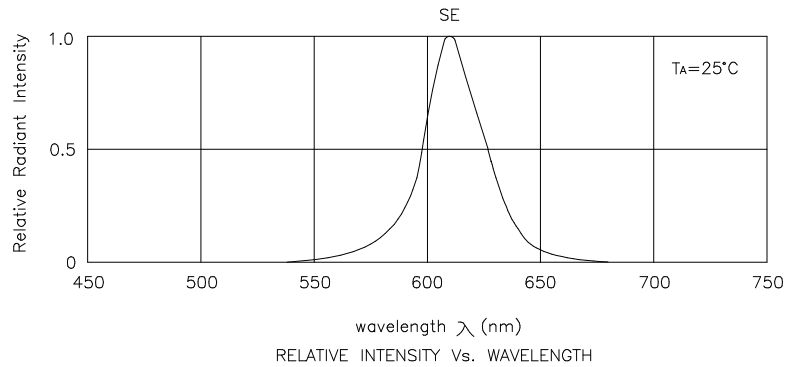
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Super Bright Orange	610		nm	I _F =20mA
λ _D	Dominate Wavelength	Super Bright Orange	601		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	Super Bright Orange	29		nm	I _F =20mA
C	Capacitance	Super Bright Orange	30		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	Super Bright Orange	2	2.5	V	I _F =20mA
I _R	Reverse Current	Super Bright Orange		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Super Bright Orange	Units
Power dissipation	75	mW
Forward Current	30	mA
Peak Forward Current [1]	195	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.



Super Bright Orange

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